

# DATA SHEET

For a complete data sheet, please also download:

- The IC06 74HC/HCT/HCU/HCMOS Logic Family Specifications
- The IC06 74HC/HCT/HCU/HCMOS Logic Package Information
- The IC06 74HC/HCT/HCU/HCMOS Logic Package Outlines

## **74HC/HCT4016** Quad bilateral switches

Product specification  
File under Integrated Circuits, IC06

December 1990

## Quad bilateral switches

## 74HC/HCT4016

## FEATURES

- Low “ON” resistance:  
160  $\Omega$  (typ.) at  $V_{CC} = 4.5$  V  
120  $\Omega$  (typ.) at  $V_{CC} = 6.0$  V  
80  $\Omega$  (typ.) at  $V_{CC} = 9.0$  V
- Individual switch controls
- Typical “break before make” built in
- Output capability: non-standard
- $I_{CC}$  category: SSI

## GENERAL DESCRIPTION

The 74HC/HCT4016 are high-speed Si-gate CMOS devices and are pin compatible with the “4016” of the

“4000B” series. They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT4016 have four independent analog switches (transmission gates).

Each switch has two input/output terminals ( $Y_n$ ,  $Z_n$ ) and an active HIGH enable input ( $E_n$ ). When  $E_n$  is connected to  $V_{CC}$ , a low bidirectional path between  $Y_n$  and  $Z_n$  is established (ON condition). When  $E_n$  is connected to ground (GND), the switch is disabled and a high impedance between  $Y_n$  and  $Z_n$  is established (OFF condition).

Current through a switch will not cause additional  $V_{CC}$  current provided the voltage at the terminals of the switch is maintained within the supply voltage range;  $V_{CC} \gg (V_Y, V_Z) \gg$  GND. Inputs  $Y_n$  and  $Z_n$  are electrically equivalent terminals.

## QUICK REFERENCE DATA

GND = 0 V;  $T_{amb} = 25$  °C;  $t_r = t_f = 6$  ns

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
$t_{PZH}/t_{PZL}$	turn “ON” time $E_n$ to $V_{OS}$	$C_L = 15$ pF; $R_L = 1$ k $\Omega$ ; $V_{CC} = 5$ V	16	17	ns
$t_{PHZ}/t_{PLZ}$	turn “OFF” time $E_n$ to $V_{OS}$		14	20	ns
$C_I$	input capacitance		3.5	3.5	pF
$C_{PD}$	power dissipation capacitance per switch	notes 1 and 2	12	12	pF
$C_S$	max. switch capacitance		5	5	pF

## Notes

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{ (C_L + C_S) \times V_{CC}^2 \times f_o \} \text{ where:}$$

$f_i$  = input frequency in MHz

$f_o$  = output frequency in MHz

$\sum \{ (C_L + C_S) \times V_{CC}^2 \times f_o \}$  = sum of outputs

$C_L$  = output load capacitance in pF

$C_S$  = max. switch capacitance in pF

$V_{CC}$  = supply voltage in V

2. For HC the condition is  $V_I = \text{GND to } V_{CC}$   
For HCT the condition is  $V_I = \text{GND to } V_{CC} - 1.5$  V

## ORDERING INFORMATION

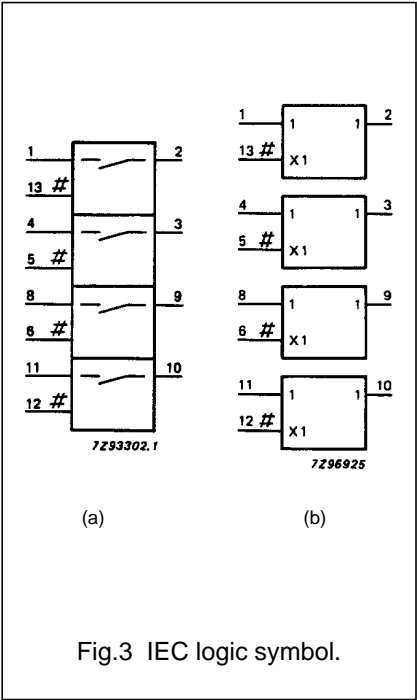
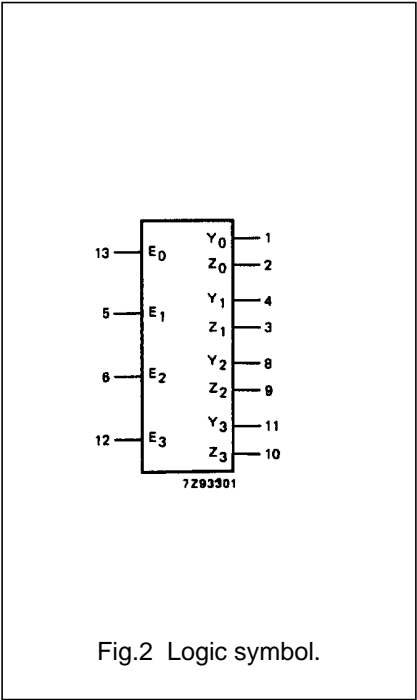
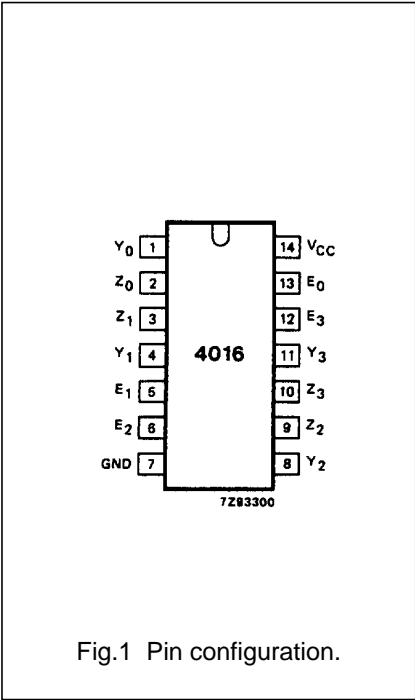
See “74HC/HCT/HCU/HCMOS Logic Package Information”.

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PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 4, 8, 11	Y <sub>0</sub> to Y <sub>3</sub>	independent inputs/outputs
7	GND	ground (0 V)
2, 3, 9, 10	Z <sub>0</sub> to Z <sub>3</sub>	independent inputs/outputs
13, 5, 6, 12	E <sub>0</sub> to E <sub>3</sub>	enable inputs (active HIGH)
14	V <sub>CC</sub>	positive supply voltage



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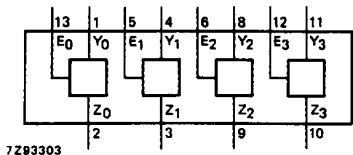


Fig.4 Functional diagram.

APPLICATIONS

- Signal gating
- Modulation
- Demodulation
- Chopper

FUNCTION TABLE

INPUT E <sub>n</sub>	CHANNEL IMPEDANCE
L	high
H	low

Notes

1. H = HIGH voltage level  
L = LOW voltage level

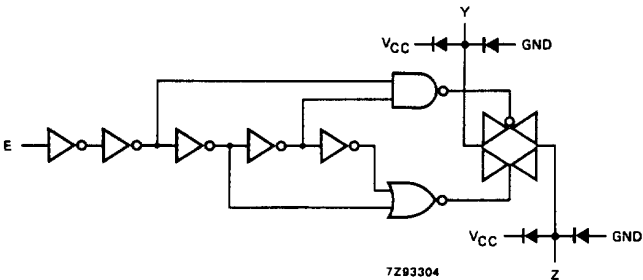


Fig.5 Schematic diagram (one switch).

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**RATINGS**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	MIN.	MAX.	UNIT	CONDITIONS
$V_{CC}$	DC supply voltage	-0.5	+11.0	V	
$\pm I_{IK}$	DC digital input diode current		20	mA	for $V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V
$\pm I_{SK}$	DC switch diode current		20	mA	for $V_S < -0.5$ V or $V_S > V_{CC} + 0.5$ V
$\pm I_S$	DC switch current		25	mA	for $-0.5$ V $< V_S < V_{CC} + 0.5$ V
$\pm I_{CC}; \pm I_{GND}$	DC $V_{CC}$ or GND current		50	mA	
$T_{stg}$	storage temperature range	-65	+150	°C	
$P_{tot}$	power dissipation per package				for temperature range: -40 to +125 °C 74HC/HCT
	plastic DIL		750	mW	above +70 °C: derate linearly with 12 mW/K
	plastic mini-pack (SO)		500	mW	above +70 °C: derate linearly with 8 mW/K
$P_S$	power dissipation per switch		100	mW	

**RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	74HC			74HCT			UNIT	CONDITIONS
		min.	typ.	max.	min.	typ.	max.		
$V_{CC}$	DC supply voltage	2.0	5.0	10.0	4.5	5.0	5.5	V	
$V_I$	DC input voltage range	GND		$V_{CC}$	GND		$V_{CC}$	V	
$V_S$	DC switch voltage range	GND		$V_{CC}$	GND		$V_{CC}$	V	
$T_{amb}$	operating ambient temperature range	-40		+85	-40		+85	°C	see DC and AC CHARACTERIS- TICS
$T_{amb}$	operating ambient temperature range	-40		+125	-40		+125	°C	
$t_r, t_f$	input rise and fall times		6.0	1000 500 400 250		6.0	500	ns	$V_{CC} = 2.0$ V $V_{CC} = 4.5$ V $V_{CC} = 6.0$ V $V_{CC} = 10.0$ V

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DC CHARACTERISTICS FOR 74HC/HCT

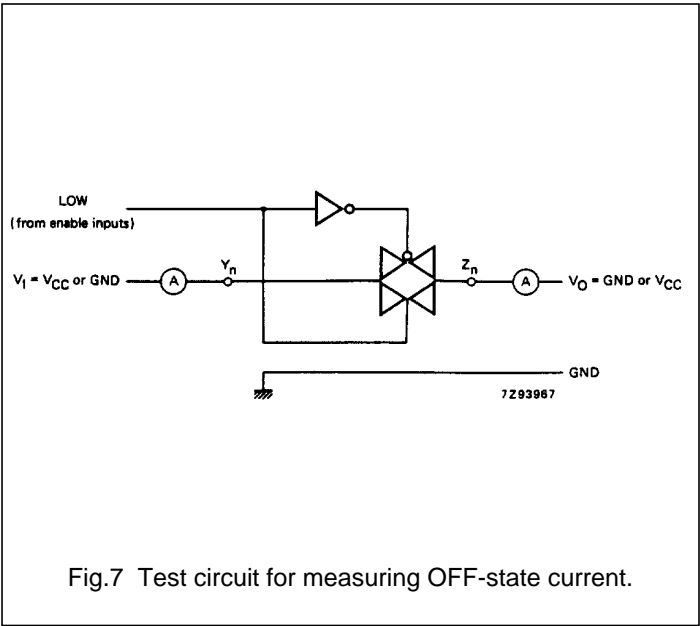
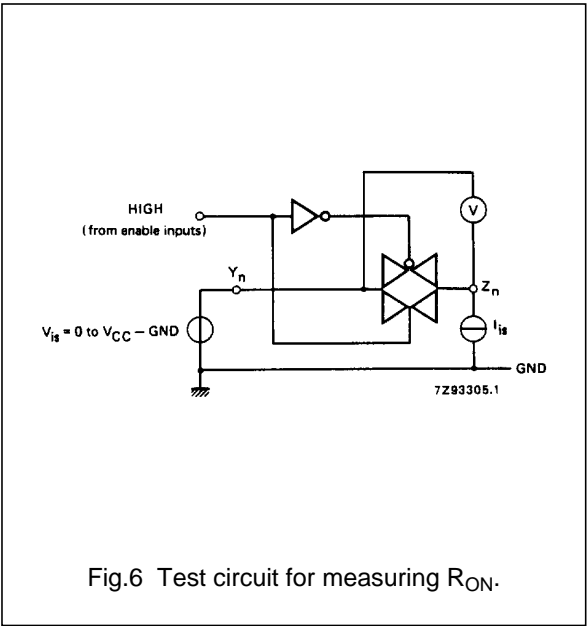
For 74HC:  $V_{CC} = 2.0, 4.5, 6.0$  and  $9.0$  V

For 74HCT:  $V_{CC} = 4.5$  V

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)							UNIT	TEST CONDITIONS			
		74HC/HCT								V <sub>CC</sub> (V)	I <sub>S</sub> (μA)	V <sub>is</sub>	V <sub>I</sub>
		+25			−40 to +85		−40 to +125						
		min.	typ.	max.	min.	max.	min.	max.					
R <sub>ON</sub>	ON resistance (peak)		—	—		—		—	Ω	2.0	100	V <sub>CC</sub> to GND	V <sub>IH</sub> or V <sub>IL</sub>
			160	320		400		480	Ω	4.5	1000		
			120	240		300		360	Ω	6.0	1000		
			85	170		213		255	Ω	9.0	1000		
R <sub>ON</sub>	ON resistance (rail)		160	—		—		—	Ω	2.0	100	GND	V <sub>IH</sub> or V <sub>IL</sub>
			80	160		200		240	Ω	4.5	1000		
			70	140		175		210	Ω	6.0	1000		
			60	120		150		180	Ω	9.0	1000		
R <sub>ON</sub>	ON resistance (rail)		170	—		—		—	Ω	2.0	100	V <sub>CC</sub>	V <sub>IH</sub> or V <sub>IL</sub>
			90	180		225		270	Ω	4.5	1000		
			80	160		200		240	Ω	6.0	1000		
			65	135		170		205	Ω	9.0	1000		
ΔR <sub>ON</sub>	maximum ΔON resistance between any two channels		— 16 12 9						Ω Ω Ω Ω	2.0 4.5 6.0 9.0		V <sub>CC</sub> to GND	V <sub>IH</sub> or V <sub>IL</sub>

Notes to the DC Characteristics

- At supply voltages approaching 2.0 V the analog switch ON-resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.
- For test circuit measuring  $R_{ON}$  see Fig.6.



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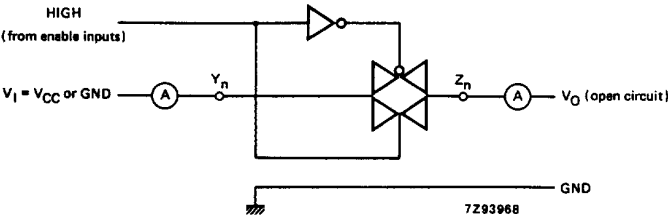


Fig.8 Test circuit for measuring ON-state current.

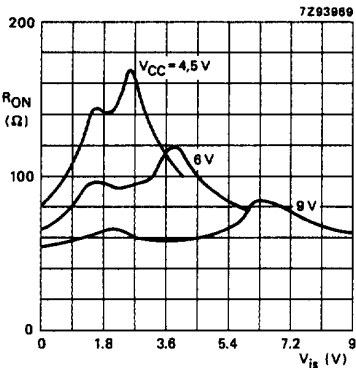


Fig.9 Typical  $R_{ON}$  as a function of input voltage  $V_{is}$  for  $V_{is} = 0$  to  $V_{CC}$ .

## Quad bilateral switches

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**DC CHARACTERISTICS FOR 74HC**

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)								UNIT	TEST CONDITIONS		
		74HC									V <sub>CC</sub> (V)	V <sub>I</sub>	OTHER
		+25			−40 to +85		−40 to +125						
		min.	typ.	max.	min.	max.	min.	max.					
V <sub>IH</sub>	HIGH level input voltage	1.5 3.15 4.2 6.3	1.2 2.4 3.2 4.3		1.5 3.15 4.2 6.3		1.5 3.15 4.2 6.3		V	2.0 4.5 6.0 9.0			
V <sub>IL</sub>	LOW level input voltage		0.8 2.1 2.8 4.3	0.50 1.35 1.80 2.70		0.50 1.35 1.80 2.70		0.50 1.35 1.80 2.70	V	2.0 4.5 6.0 9.0			
±I <sub>I</sub>	input leakage current			0.1 0.2		1.0 2.0		1.0 2.0	μA	6.0 10.0	V <sub>CC</sub> or GND		
±I <sub>S</sub>	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	10.0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> – GND (see Fig.7)	
±I <sub>S</sub>	analog switch ON-state current			0.1		1.0		1.0	μA	10.0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> – GND (see Fig.8)	
I <sub>CC</sub>	quiescent supply current			2.0 4.0		20.0 40.0		40.0 80.0	μA	6.0 10.0	V <sub>CC</sub> or GND	V <sub>is</sub> = GND or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or GND	

**AC CHARACTERISTICS FOR 74HC**GND = 0 V; t<sub>r</sub> = t<sub>f</sub> = 6 ns; C<sub>L</sub> = 50 pF

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)							UNIT	TEST CONDITIONS	
		74HC								V <sub>CC</sub> (V)	OTHER
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
t <sub>PHL</sub> / t <sub>PLH</sub>	propagation delay V <sub>is</sub> to V <sub>os</sub>		17 6 5 4	60 12 10 8		75 15 13 10		90 18 15 12	ns	2.0 4.5 6.0 9.0	R <sub>L</sub> = ∞; C <sub>L</sub> = 50 pF (see Fig.16)
t <sub>PZH</sub> / t <sub>PZL</sub>	turn “ON” time E <sub>n</sub> to V <sub>os</sub>		52 19 15 11	190 38 32 28		240 48 41 35		235 57 48 42	ns	2.0 4.5 6.0 9.0	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 17 and 18)
t <sub>PHZ</sub> / t <sub>PLZ</sub>	turn “OFF” time E <sub>n</sub> to V <sub>os</sub>		47 17 14 13	145 29 25 22		180 36 31 28		220 44 38 33	ns	2.0 4.5 6.0 9.0	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 17 and 18)



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**DC CHARACTERISTICS FOR 74HCT**

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)							UNIT	TEST CONDITIONS		
		74HCT								V <sub>CC</sub> (V)	V <sub>I</sub>	OTHER
		+25			−40 to +85		−40 to +125					
		min.	typ.	max.	min.	max.	min.	max.				
V <sub>IH</sub>	HIGH level input voltage	2.0	1.6		2.0		2.0		V	4.5 to 5.5		
V <sub>IL</sub>	LOW level input voltage		1.2	0.8		0.8		0.8	V	4.5 to 5.5		
±I <sub>I</sub>	input leakage current			0.1		1.0		1.0	μA	5.5	V <sub>CC</sub> or GND	
±I <sub>S</sub>	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	5.5	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> – GND (see Fig.7)
±I <sub>S</sub>	analog switch ON-state current			0.1		1.0		1.0	μA	5.5	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> – GND (see Fig.8)
I <sub>CC</sub>	quiescent supply current			2.0		20.0		40.0	μA	4.5 to 5.5	V <sub>CC</sub> or GND	V <sub>is</sub> = GND or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or GND
ΔI <sub>CC</sub>	additional quiescent supply current per input pin for unit load coefficient is 1 (note 1)		100	360		450		490	μA	4.5 to 5.5	V <sub>CC</sub> –2.1V	other inputs at V <sub>CC</sub> or GND

**Note**

- The value of additional quiescent supply current (ΔI<sub>CC</sub>) for a unit load of 1 is given here.  
To determine ΔI<sub>CC</sub> per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
E <sub>N</sub>	1.00

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**AC CHARACTERISTICS FOR 74HCT**GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)							UNIT	TEST CONDITIONS	
		74HCT								V <sub>CC</sub> (V)	OTHER
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
t <sub>PHL</sub> / t <sub>PLH</sub>	propagation delay V <sub>is</sub> to V <sub>os</sub>		6	12		15		18	ns	4.5	R <sub>L</sub> = ∞; C <sub>L</sub> = 50 pF (see Fig.16)
t <sub>PZH</sub>	turn “ON” time E <sub>n</sub> to V <sub>os</sub>		19	35		44		53	ns	4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 17 and 18)
t <sub>PZL</sub>	turn “ON” time E <sub>n</sub> to V <sub>os</sub>		20	35		44		53	ns	4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 17 and 18)
t <sub>PHZ</sub> / t <sub>PLZ</sub>	turn “OFF” time E <sub>n</sub> to V <sub>os</sub>		23	35		44		53	ns	4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 17 and 18)

**ADDITIONAL AC CHARACTERISTICS FOR 74HC/HCT****Recommended conditions and typical values**GND = 0 V;  $t_r = t_f = 6$  ns

SYMBOL	PARAMETER	typ.	UNIT	$V_{CC}$ (V)	$V_{is(p-p)}$ (V)	CONDITIONS
	sine-wave distortion $f = 1$ kHz	0.80 0.40	% %	4.5 9.0	4.0 8.0	$R_L = 10$ k $\Omega$ ; $C_L = 50$ pF (see Fig.14)
	sine-wave distortion $f = 10$ kHz	2.40 1.20	% %	4.5 9.0	4.0 8.0	$R_L = 10$ k $\Omega$ ; $C_L = 50$ pF (see Fig.14)
	switch “OFF” signal feed-through	−50 −50	dB dB	4.5 9.0	note 3	$R_L = 600$ $\Omega$ ; $C_L = 50$ pF; $f = 1$ MHz (see Figs 10 and 15)
	crosstalk between any two switches	−60 −60	dB dB	4.5 9.0	note 3	$R_L = 600$ $\Omega$ ; $C_L = 50$ pF; $f = 1$ MHz (see Fig.12)
$V_{(p-p)}$	crosstalk voltage between enable or address input to any switch (peak-to-peak value)	110 220	mV mV	4.5 9.0		$R_L = 600$ $\Omega$ ; $C_L = 50$ pF; $f = 1$ MHz ( $E_n$ , square wave between $V_{CC}$ and GND, $t_r = t_f = 6$ ns) (see Fig.13)
$f_{max}$	minimum frequency response (−3dB)	150 160	MHz MHz	4.5 9.0	note 4	$R_L = 50$ $\Omega$ ; $C_L = 10$ pF (see Figs 11 and 14)
$C_S$	maximum switch capacitance	5	pF			

**Notes**

1.  $V_{is}$  is the input voltage at a  $Y_n$  or  $Z_n$  terminal, whichever is assigned as an input.
2.  $V_{os}$  is the output voltage at a  $Y_n$  or  $Z_n$  terminal, whichever is assigned as an output.
3. Adjust input voltage  $V_{is}$  to 0 dBm level (0 dBm = 1 mW into 600  $\Omega$ ).
4. Adjust input voltage  $V_{is}$  to 0 dBm level at  $V_{os}$  for 1 MHz (0 dBm = 1 mW into 50  $\Omega$ ).

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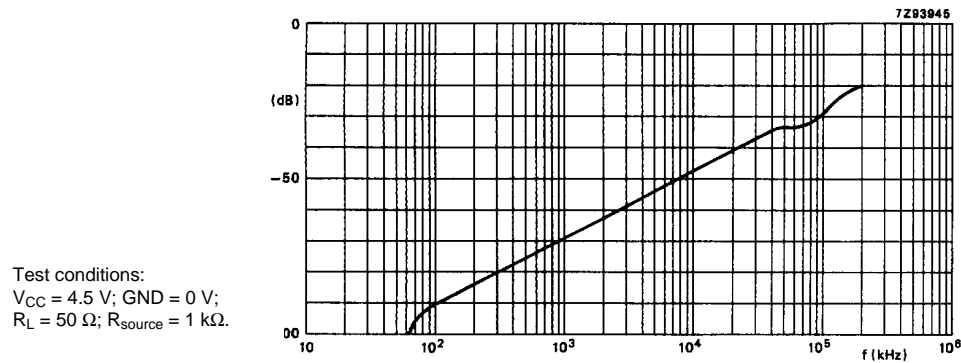


Fig.10 Typical switch "OFF" signal feed-through as a function of frequency.

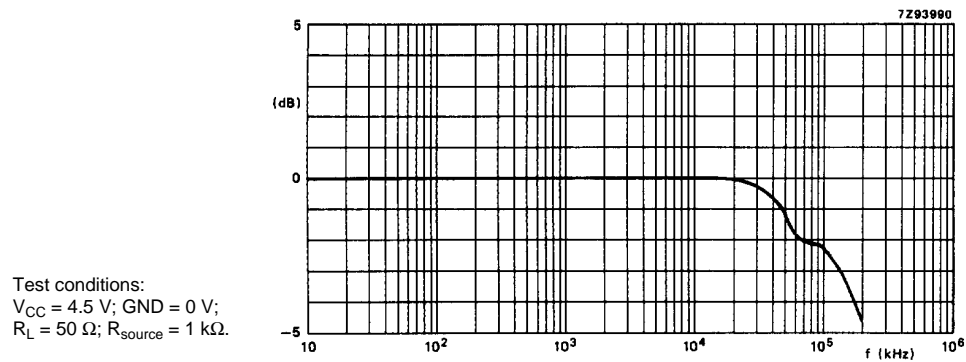


Fig.11 Typical frequency response.

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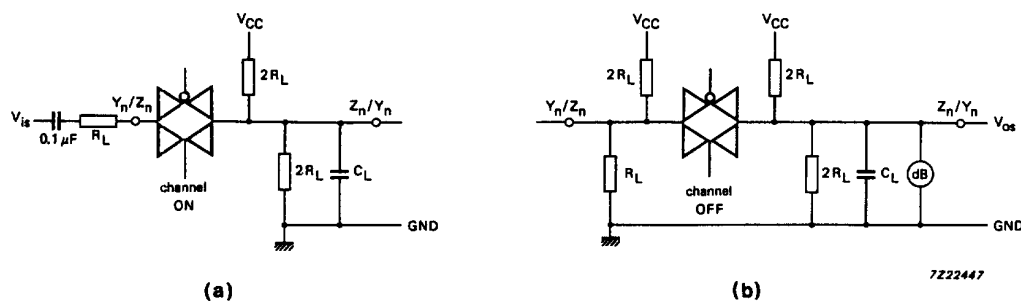


Fig.12 Test circuit for measuring crosstalk between any two switches.  
(a) channel ON condition; (b) channel OFF condition.

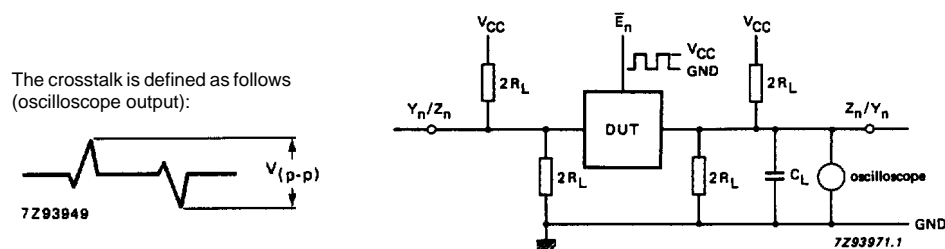


Fig.13 Test circuit for measuring crosstalk between control and any switch.

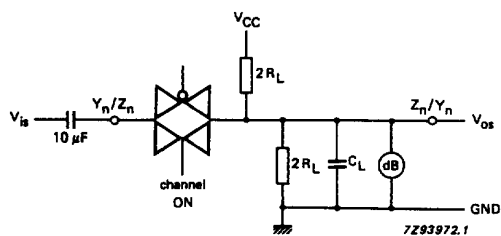


Fig.14 Test circuit for measuring sine-wave distortion and minimum frequency response.

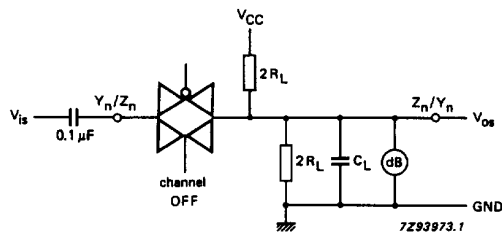


Fig.15 Test circuit for measuring switch "OFF" signal feed-through.

## Quad bilateral switches

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## AC WAVEFORMS

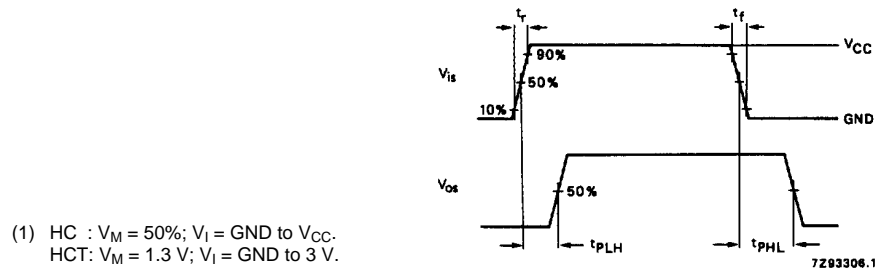
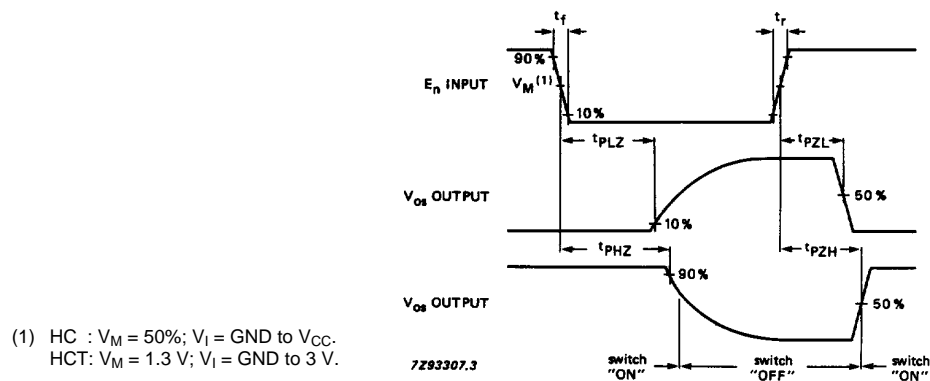
Fig.16 Waveforms showing the input ( $V_{is}$ ) to output ( $V_{os}$ ) propagation delays.

Fig.17 Waveforms showing the turn-ON and turn-OFF times.

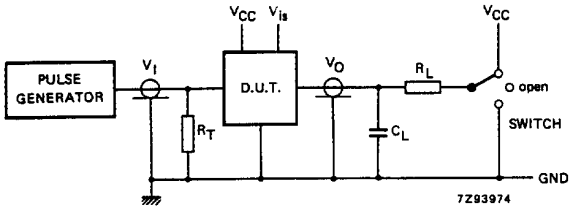
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TEST CIRCUIT AND WAVEFORMS

Conditions

TEST	SWITCH	V <sub>is</sub>
t <sub>PZH</sub>	GND	V <sub>CC</sub>
t <sub>PZL</sub>	V <sub>CC</sub>	GND
t <sub>PHZ</sub>	GND	V <sub>CC</sub>
t <sub>PLZ</sub>	V <sub>CC</sub>	GND
others	open	pulse

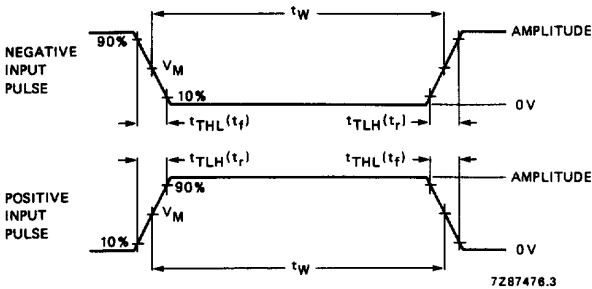


C<sub>L</sub> = load capacitance including jig and probe capacitance (see AC CHARACTERISTICS for values).  
R<sub>T</sub> = termination resistance should be equal to the output impedance Z<sub>O</sub> of the pulse generator.  
t<sub>r</sub> = t<sub>f</sub> = 6 ns; when measuring f<sub>max</sub>, there is no constraint t<sub>r</sub>, t<sub>f</sub> with 50% duty factor.

FAMILY	AMPLITUDE	V <sub>M</sub>	t <sub>r</sub> ; t <sub>f</sub>	
			f <sub>max</sub> ; PULSE WIDTH	OTHER
74HC	V <sub>CC</sub>	50%	< 2 ns	6 ns
74HCT	3.0 V	1.3 V	< 2 ns	6 ns

Fig.18 Test circuit for measuring AC performance.

C<sub>L</sub> = load capacitance including jig and probe capacitance (see AC CHARACTERISTICS for values).  
R<sub>T</sub> = termination resistance should be equal to the output impedance Z<sub>O</sub> of the pulse generator.  
t<sub>r</sub> = t<sub>f</sub> = 6 ns; when measuring f<sub>max</sub>, there is no constraint t<sub>r</sub>, t<sub>f</sub> with 50% duty factor.



FAMILY	AMPLITUDE	V <sub>M</sub>	t <sub>r</sub> ; t <sub>f</sub>	
			f <sub>max</sub> ; PULSE WIDTH	OTHER
74HC	V <sub>CC</sub>	50%	< 2 ns	6 ns
74HCT	3.0 V	1.3 V	< 2 ns	6 ns

Fig.19 Input pulse definitions.

PACKAGE OUTLINES

See *“74HC/HCT/HCU/HCMOS Logic Package Outlines”*.